

MMBTA42L, SMMBTA42L, MMBTA43L

High Voltage Transistors

NPN Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Collector – Emitter Voltage MMBTA42, SMMBTA42 MMBTA43	V_{CEO}	300 200	Vdc
Collector – Base Voltage MMBTA42, SMMBTA42 MMBTA43	V_{CBO}	300 200	Vdc
Emitter – Base Voltage MMBTA42, SMMBTA42 MMBTA43	V_{EBO}	6.0 6.0	Vdc
Collector Current – Continuous	I_C	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

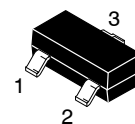
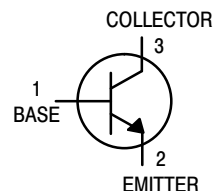
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



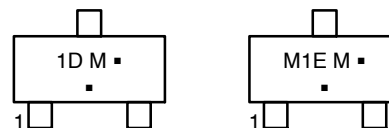
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SOT-23 (TO-236)
CASE 318
STYLE 6

MARKING DIAGRAMS



1D = MMBTA42LT, SMMBTA42L

M1E = MMBTA43LT

M = Date Code*

▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MMBTA42L, SMMBTA42L, MMBTA43L

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 3) (I _C = 1.0 mA _{dc} , I _B = 0)	V _{(BR)CEO}	300 200	– –	V _{dc}
Collector – Base Breakdown Voltage (I _C = 100 µA _{dc} , I _E = 0)	V _{(BR)CBO}	300 200	– –	V _{dc}
Emitter – Base Breakdown Voltage (I _E = 100 µA _{dc} , I _C = 0)	V _{(BR)EBO}	6.0	–	V _{dc}
Collector Cutoff Current (V _{CB} = 200 V _{dc} , I _E = 0) (V _{CB} = 160 V _{dc} , I _E = 0)	I _{CBO}	– –	0.1 0.1	µA _{dc}
Emitter Cutoff Current (V _{EB} = 6.0 V _{dc} , I _C = 0) (V _{EB} = 4.0 V _{dc} , I _C = 0)	I _{EBO}	– –	0.1 0.1	µA _{dc}
ON CHARACTERISTICS (Note 3)				
DC Current Gain (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 30 mA _{dc} , V _{CE} = 10 V _{dc})	Both Types Both Types MMBTA42, SMMBTA42 MMBTA43	h _{FE} 25 40 40 40	– – – –	–
Collector – Emitter Saturation Voltage (I _C = 20 mA _{dc} , I _B = 2.0 mA _{dc})	MMBTA42, SMMBTA42 MMBTA43	V _{CE(sat)} – –	0.5 0.5	V _{dc}
Base – Emitter Saturation Voltage (I _C = 20 mA _{dc} , I _B = 2.0 mA _{dc})		V _{BE(sat)} –	0.9	V _{dc}
SMALL – SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product (I _C = 10 mA _{dc} , V _{CE} = 20 V _{dc} , f = 100 MHz)	f _T	50	–	MHz
Collector – Base Capacitance (V _{CB} = 20 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{cb}	– –	3.0 4.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%.

TYPICAL CHARACTERISTICS

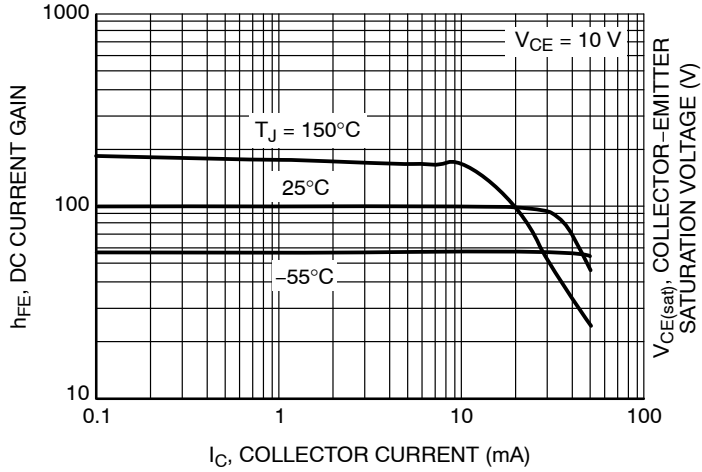


Figure 1. DC Current Gain

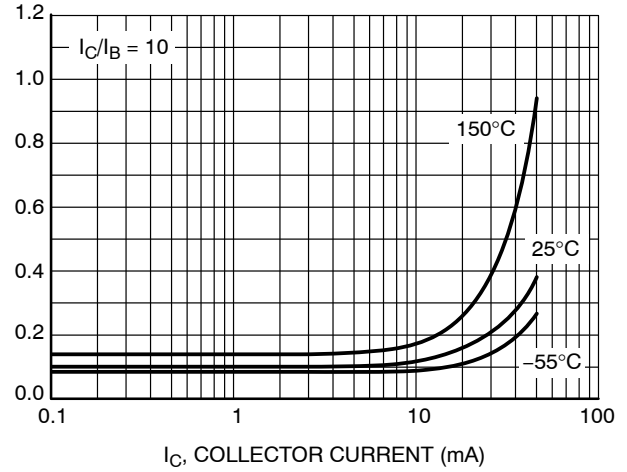


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

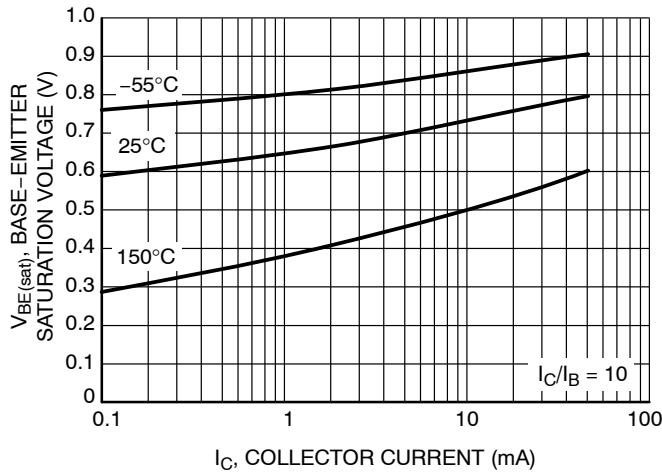


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

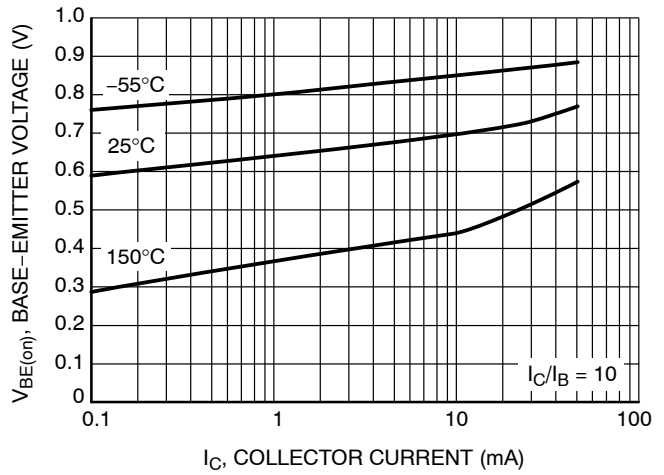


Figure 4. Base-Emitter On Voltage vs. Collector Current

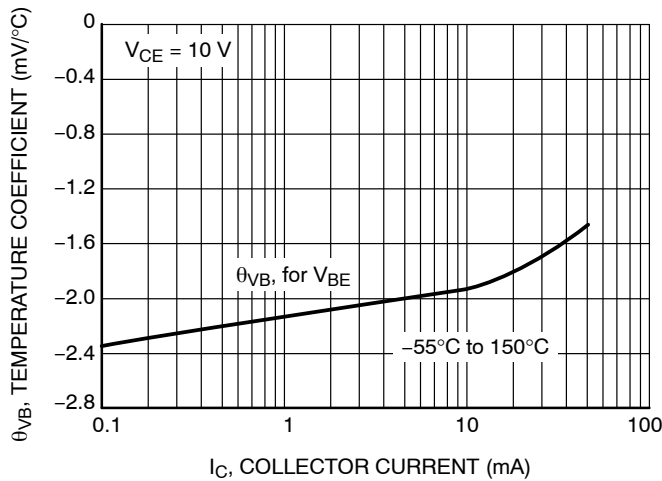


Figure 5. Base-Emitter Temperature Coefficient

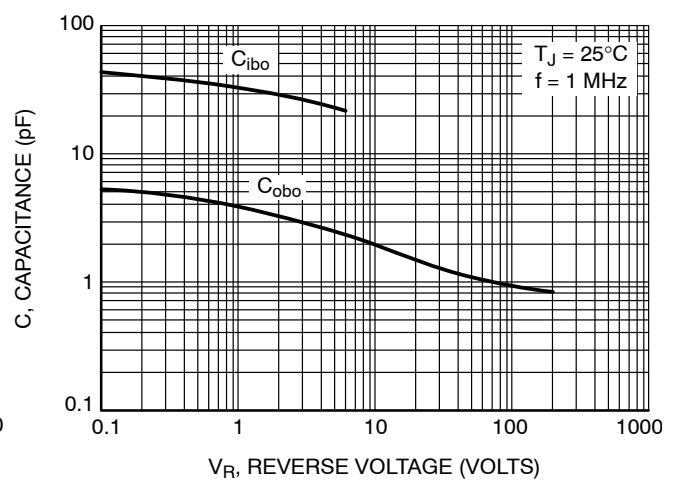


Figure 6. Capacitance

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TYPICAL CHARACTERISTICS

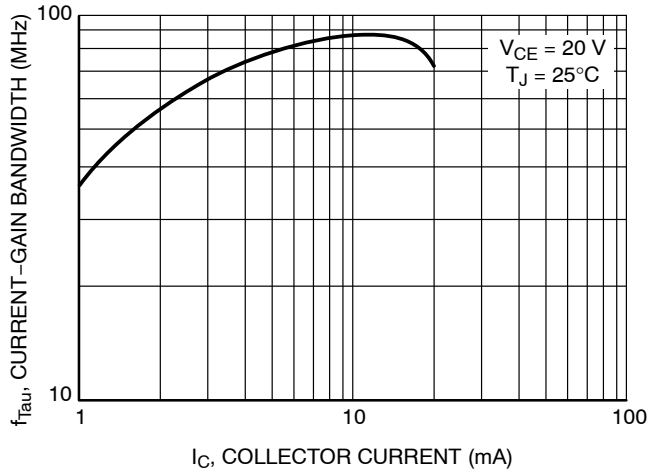


Figure 7. Current-Gain — Bandwidth Product

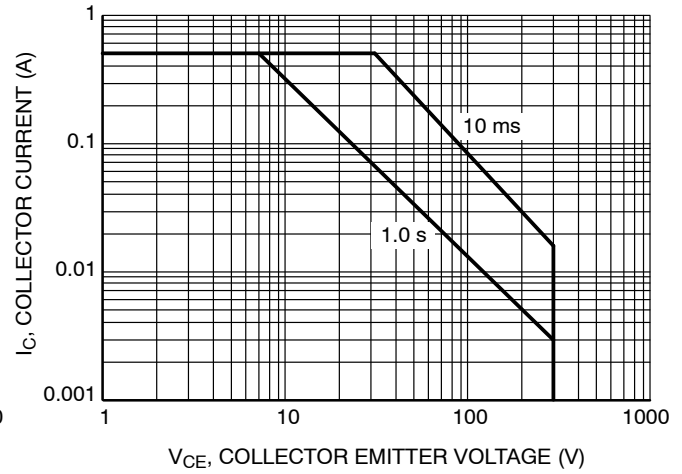


Figure 8. Safe Operating Area

ORDERING INFORMATION

Device Order Number	Package Type	Shipping [†]
MMBTA42LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMBTA42LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBTA42LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
SMMBTA42LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
MMBTA43LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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